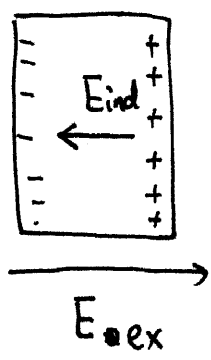


§ Electrical static properties of conductors

① $E = 0$ inside a conductor. — electro-static screening

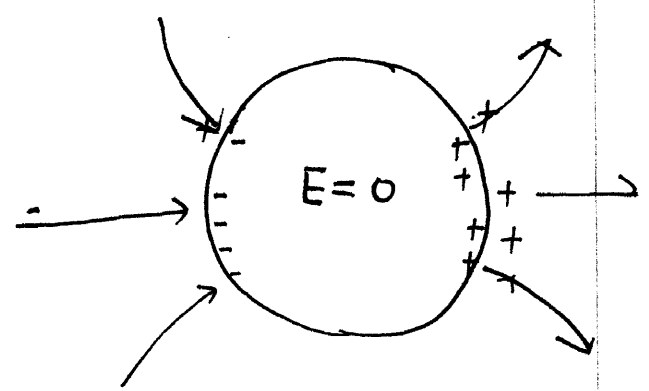


mobile charge. External fields cause charge redistribution, to screen the external field which generate compensate fields

if $\vec{E}_{tot} = \vec{E}_{ex} + \vec{E}_{ind} \neq 0$, then charge will still be driven to move. Equilibrium is reached at $\vec{E}_{tot} = 0$.

Even inside a metallic shell, if there's no charge inside, you also have $E = 0$.

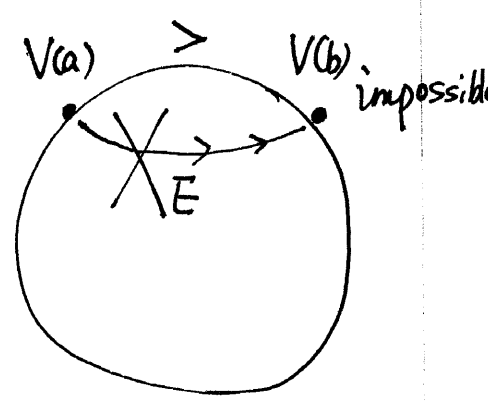
② the surface of a conductor



has equal potential.

otherwise, electric charge will move follow the potential difference.

Inside a metallic shell, ~~there~~ if there's no charge. There should be no electric field lines. Otherwise, the field line has to



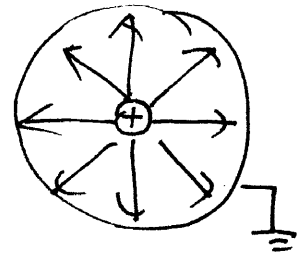
Electric line can't form loop in electro-statics. (2)

start from the shell and end at shell. Then the shell is n't equal-potential! Thus $\vec{E} = 0$ inside the metallic shell.

But if there does exist charge inside the shell, \vec{E} can exist.

(3) no free charge inside the bulk of metal.

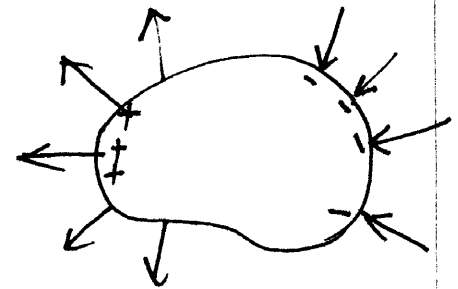
Any net charge is on the surface.



(4) \vec{E} is perpendicular to surface of conductor.

$\vec{E} = -\nabla V(r)$. the surface of conductor is equal-potential

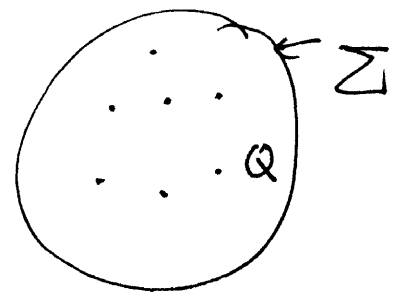
$\Rightarrow \vec{E} \perp \text{surface}$.



Question: Suppose we confine the charge within some region with the boundary of Σ .

→ the minimum electro-static energy configuration requires

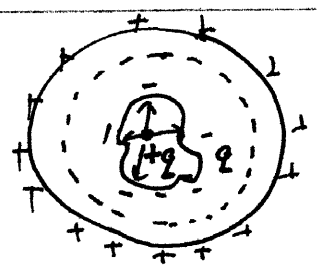
that all charges move to the surface!



This the same problem of the equilibrium charge distribution of a metal with net charge.

examp: electric field of a spherical sphere with a cavity.

+q inside the cavity attracts -q on the inner surface. Then +q charge goes uniformly to the outer surface of the sphere.

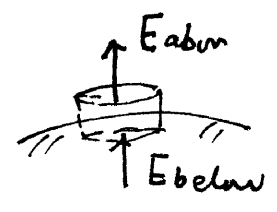


Because the electric field in the bulk is zero, the only part important is the outer surface.

$$\Rightarrow \vec{E} = \frac{q}{r^2} \hat{e}_r.$$

§ surface charge

according to the boundary condition



$$E_{\perp, above} - E_{\perp, below} = 4\pi\sigma$$

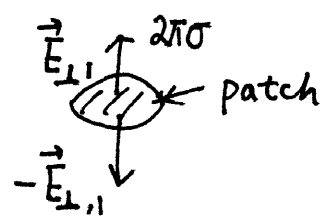
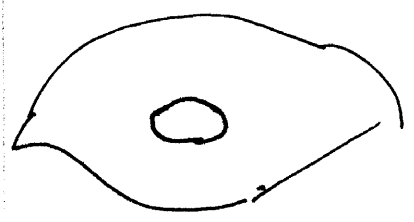
and $E_{\perp, below} = 0 \Rightarrow E_{\perp, above} = 4\pi\sigma$. or $\sigma = -\frac{1}{4\pi} \frac{\partial V}{\partial n}$.

What's the force exerted on the surface?

You might think the force density: $\vec{f} = \sigma \cdot E_{\perp} \hat{n}$, but actually

this is not true. The force is ~~the~~ exerted by the fields generated by other parts of the surface.

on one patch



Let us consider a small patch with charge density σ , it generates \vec{E} along the norm in the opposited direction of $\pm 2\pi\sigma \hat{n}$.

The field generated by other parts of the surface should be

continuous at this patch \vec{E}_{other} .

we know $\vec{E}_{\text{other}} - \vec{E}_{\perp} = 0$ (inside)

$$\vec{E}_{\text{other}} + \vec{E}_{\perp} = 4\pi\sigma \hat{n}$$

$$\Rightarrow \vec{E}_{\text{other}} = 2\pi\sigma \hat{n}$$

\Rightarrow

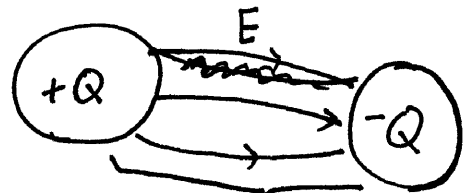
$$\vec{f} = \vec{E}_{\text{other}} \sigma = 2\pi\sigma^2 \hat{n}$$

outward electro-static pressure on the surface.

§ Capacitors — the ability to store charge

$$V = - \int_{-}^{+} \vec{E} \cdot d\vec{l}$$

$C = \frac{Q}{V}$. Q is proportional to V . $\Rightarrow C$ is a const



$$V = V_+ - V_-$$

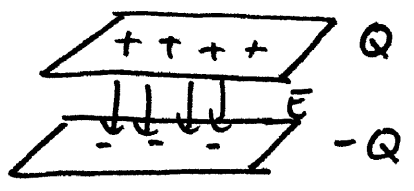
which depends on the shape of conductors.

If we double the charge distribution on each surface, ~~by a factor~~ this is a linear system, the \vec{E} field doubles $\Rightarrow V$ doubles.

C is unchanged!

example: ① planar plate capacitor

$$E = 4\pi\sigma = \frac{Q}{4\pi A}, \quad V = E \cdot d$$

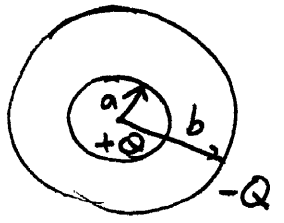


$$\Rightarrow C = \frac{Q}{V} = \frac{Q \cdot 4\pi A}{Q d} = 4\pi A/d \quad \text{in Gauss unit}$$

C has the unit of length

② $E = \frac{Q}{r^2}$

$$V = + \int_a^b \vec{E} \cdot d\vec{r} = Q \left[\frac{1}{a} - \frac{1}{b} \right] = Q \frac{b-a}{ab}$$



$$\Rightarrow C = \frac{Q}{V} = \frac{ab}{a-b}$$

Energy stored in the capacitor: Considering a charging process

$$dw = V dq = \frac{q}{C} dq$$

$$\Rightarrow W = \int_0^Q \frac{q dq}{C} = \frac{Q^2}{2C} = \frac{1}{2} CV^2$$

check for plate capacitor

~~$$W = \text{Vol} \cdot \frac{E^2}{8\pi} = A \cdot d \cdot \frac{(4\pi\sigma)^2}{8\pi} = \frac{2\pi\sigma^2}{1} Ad = \frac{(Q/A)^2 4\pi d}{2 A}$$~~

~~$$= \frac{Q^2}{2A}$$~~